

3.3V CMOS 16-BIT BUS TRANSCEIVER WITH 3-STATE OUTPUTS AND 5 VOLT TOLERANT I/O

2DIR

IDT74LVCR162245A

FEATURES:

- Typical tsk(o) (Output Skew) < 250ps
- ESD > 2000V per MIL-STD-883, Method 3015; > 200V using machine model (C = 200pF, R = 0)
- Vcc = 3.3V ± 0.3V, Normal Range
- Vcc = 2.7V to 3.6V, Extended Range
- CMOS power levels (0.4µ W typ. static)
- · All inputs, outputs, and I/O are 5V tolerant
- Supports hot insertion
- Available in SSOP and TSSOP packages

DRIVE FEATURES:

- Balanced Output Drivers: ±12mA
- Low switching noise

APPLICATIONS:

- 5V and 3.3V mixed voltage systems
- · Data communication and telecommunication systems

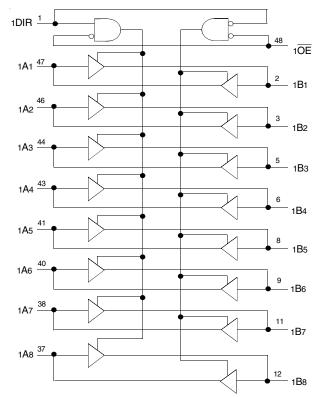
FUNCTIONAL BLOCK DIAGRAM

DESCRIPTION:

This 16-bit bus transceiver is built using advanced dual metal CMOS technology. This high-speed, low power transceiver is ideal for asynchronous communication between two busses (A and B). The Direction and Output Enable controls are designed to operate this device as either two independent 8-bit transceivers or one 16-bit transceiver. The direction control pin (DIR) controls the direction of data flow. The output enable pin (\overline{OE}) overrides the direction control and disables both ports. All inputs are designed with hysteresis for improved noise margin.

All pins can be driven from either 3.3V or 5V devices. This feature allows the use of this device as a translator in a mixed 3.3V/5V supply system.

The LVCR162245A has series resistors in the device output structure which will significantly reduce line noise when used with light loads. The driver has been designed to drive \pm 12mA at the designated threshold levels.





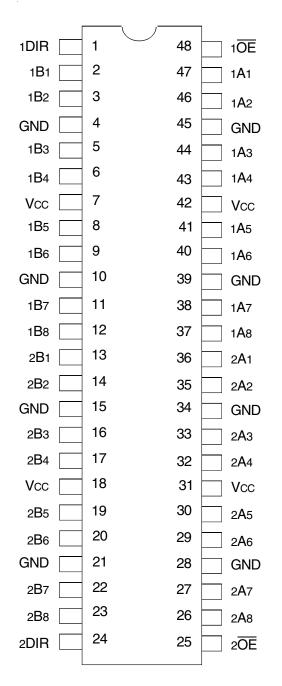


25 2<mark>0E</mark> 2A1 - 36 ¹³____ 2B1 2**A**2 14 2B2 2A3 16 2B3 2**A**4 17 2**B**4 2**A**5 19 2B5 2A6 20 -2B6 2A7 22 2B7 2**A**8 23 2B8

IDT74LVCR162245A 3.3V CMOS 16-BIT BUS TRANSCEIVER WITH 3-STATE OUTPUTS

INDUSTRIAL TEMPERATURE RANGE

PINCONFIGURATION



SSOP/ TSSOP TOP VIEW

ABSOLUTE MAXIMUM RATINGS⁽¹⁾

Symbol	Description	Max	Unit
VTERM ⁽²⁾	Terminal Voltage with Respect to GND	–0.5 to +6.5	V
VTERM ⁽³⁾	Terminal Voltage with Respect to GND	-0.5 to +6.5	V
Tstg	Storage Temperature	-65 to +150	°C
Ιουτ	DC Output Current	-50 to +50	mA
Ік Іок	Continuous Clamp Current, -5 VI < 0 or Vo < 0		mA
lcc Iss	Continuous Current through each Vcc or GND	±100	mA

NOTES:

 Stresses greater than those listed under ABSOLUTE MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

2. Vcc terminals.

3. All terminals except Vcc.

CAPACITANCE (TA = +25°C, F = 1.0MHz)

Symbol	Parameter ⁽¹⁾	Conditions	Тур.	Max.	Unit
Cin	Input Capacitance	VIN = 0V	4.5	6	pF
Соит	Output Capacitance	Vout = 0V	6.5	8	pF
Ci/o	I/O Port Capacitance	VIN = 0V	6.5	8	pF

NOTE:

1. As applicable to the device type.

PINDESCRIPTION

Pin Names	Description	
xŌĒ	xOE Output Enable Input (Active LOW)	
xDIR	Direction Control Input	
x A x Side A Inputs or 3-State Outputs		
хВх	Side B Inputs or 3-State Outputs	

FUNCTION TABLE (EACH 8-BIT SECTION)⁽¹⁾

Inp	outs	
xOE	xDIR	Outputs
L	L	Bus B Data to Bus A
L	Н	Bus A Data to Bus B
Н	Х	Isolation

NOTE:

1. H = HIGH Voltage Level

X = Don't Care

L = LOW Voltage Level

DC ELECTRICAL CHARACTERISTICS OVER OPERATING RANGE

Following Conditions Apply Unless Otherwise Specified:

Operating Condition: $TA = -40^{\circ}C$ to $+85^{\circ}C$

Symbol	Parameter	Test Co	nditions	Min.	Тур. ⁽¹⁾	Max.	Unit
Vih	Input HIGH Voltage Level	Vcc = 2.3V to 2.7V		1.7	-	_	V
		Vcc = 2.7V to 3.6V		2	-	_	
Vil	Input LOW Voltage Level	Vcc = 2.3V to 2.7V		_	_	0.7	V
		Vcc = 2.7V to 3.6V		-	_	0.8	
Ін Іц	Input Leakage Current	Vcc = 3.6V	VI = 0 to 5.5V	-	-	±5	μA
Iozh Iozl	High Impedance Output Current (3-State Output pins)	Vcc = 3.6V	Vo = 0 to 5.5V	-	-	±10	μA
IOFF	Input/Output Power Off Leakage	Vcc = 0V, VIN or Vo \leq 5.5V			-	±50	μA
Vik	Clamp Diode Voltage	Vcc = 2.3V, IIN = -18mA			-0.7	-1.2	V
Vн	Input Hysteresis	Vcc = 3.3V			100	_	mV
ICCL ICCH	Quiescent Power Supply Current	VCC = 3.6V	VIN = GND or VCC	_	-	10	μA
lccz			$3.6 \le VIN \le 5.5V^{(2)}$	-	—	10	
∆lcc	Quiescent Power Supply Current Variation	One input at Vcc - 0.6V, other inputs at Vcc or GND		-	_	500	μA

NOTES:

1. Typical values are at Vcc = 3.3V, +25°C ambient.

2. This applies in the disabled state only.

OUTPUT DRIVE CHARACTERISTICS

Symbol	Parameter	TestC	onditions ⁽¹⁾	Min.	Max.	Unit
Vон	Voн Output HIGH Voltage	Vcc = 2.3V to 3.6V	Iон = - 0.1mA	Vcc-0.2	_	V
		Vcc = 2.3V	Iон = – 4mA	1.9	_	
			Iон = – 6mA	1.7	_	
		Vcc = 2.7V	Iон = – 4mA	2.2	_	
			Iон = – 8mA	2	_	
		Vcc = 3V	Iон = – 6mA	2.4	_	
			Iон = – 12mA	2	_	
VoL Output LOW Voltage	Vcc = 2.3V to 3.6V	IOL = 0.1mA	—	0.2	V	
		Vcc = 2.3V	IOL = 4mA	—	0.4	
			IOL = 6mA	_	0.55	
		Vcc = 2.7V	IOL = 4mA	—	0.4	
			IOL = 8mA	_	0.6	
		Vcc = 3V	IOL = 6mA	—	0.55	
			IOL = 12mA	_	0.8	Ĩ

NOTE:

1. VIH and VIL must be within the min. or max. range shown in the DC ELECTRICAL CHARACTERISTICS OVER OPERATING RANGE table for the appropriate Vcc range. TA = − 40°C to + 85°C.

OPERATING CHARACTERISTICS, Vcc = $3.3V \pm 0.3V$, TA = $25^{\circ}C$

Symbol	Parameter	Test Conditions	Typical	Unit
Cpd	Power Dissipation Capacitance per Transceiver Outputs enabled	CL = 0pF, f = 10Mhz	39	pF
Cpd	Power Dissipation Capacitance per Transceiver Outputs disabled		4	

SWITCHING CHARACTERISTICS⁽¹⁾

		Vcc =	2.7V	Vcc = 3.3	V ± 0.3V	
Symbol	Parameter	Min.	Max.	Min.	Max.	Unit
t PLH	Propagation Delay	—	5.7	1.5	4.8	ns
t PHL	xAx to xBx, xBx to xAx					
tрzн	Output Enable Time	—	7.9	1.5	6.3	ns
tPZL	xOE to xAx or xBx					
tphz	Output Disable Time	—	8.3	2.2	7.4	ns
tPLZ	xOE to xAx or xBx					
tsk(o)	Output Skew ⁽²⁾	—	_	_	500	ps

NOTES:

1. See TEST CIRCUITS AND WAVEFORMS. TA = -40° C to $+85^{\circ}$ C.

2. Skew between any two outputs of the same package and switching in the same direction.

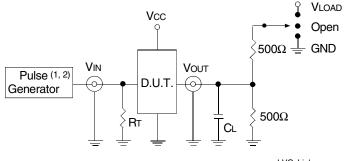
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INDUSTRIAL TEMPERATURE RANGE

TEST CIRCUITS AND WAVEFORMS

TESTCONDITIONS

Symbol	$Vcc^{(1)} = 3.3V \pm 0.3V$	Vcc ⁽¹⁾ =2.7V	Vcc ⁽²⁾ =2.5V±0.2V	Unit
Vload	6	6	2 x Vcc	V
Vih	2.7	2.7	Vcc	V
Vτ	1.5	1.5	Vcc / 2	V
Vlz	300	300	150	mV
Vhz	300	300	150	mV
Cl	50	50	30	рF





Test Circuit for All Outputs

DEFINITIONS:

CL = Load capacitance: includes jig and probe capacitance.

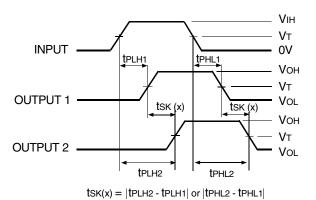
RT = Termination resistance: should be equal to ZOUT of the Pulse Generator.

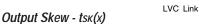
NOTES:

1. Pulse Generator for All Pulses: Rate \leq 10MHz; tF \leq 2.5ns; tR \leq 2.5ns. 2. Pulse Generator for All Pulses: Rate \leq 10MHz; tF \leq 2ns; tR \leq 2ns.

SWITCH POSITION

Test	Switch
Open Drain Disable Low Enable Low	Vload
Disable High Enable High	GND
All Other Tests	Open

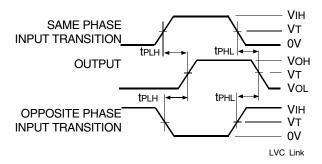




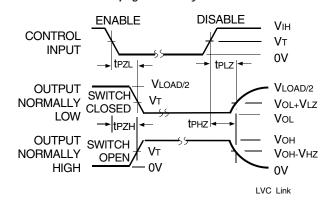
NOTES:

1. For tsk(o) OUTPUT1 and OUTPUT2 are any two outputs.

2. For tsk(b) OUTPUT1 and OUTPUT2 are in the same bank.



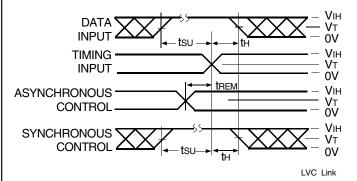
Propagation Delay



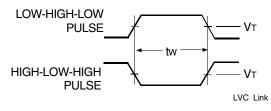
Enable and Disable Times

NOTE:

1. Diagram shown for input Control Enable-LOW and input Control Disable-HIGH.



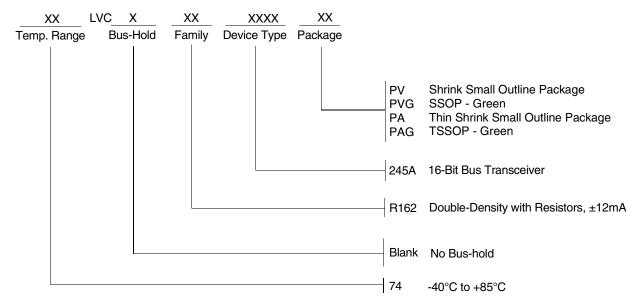




Pulse Width

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ORDERING INFORMATION





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